



PEN: The material of choice?

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- Mechanical properties
- Applications and commercial availability
 - Radiopurity
 - R&D ond lamination
 - Scintillation properties
 - How could PEN help us?





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Mechanical properties of PEN





Mechanical properties of PEN

Taken from Godfellows

Mechanical Properties

Chemical Resistance

Acids - concentrated	Goo
Acids - dilute	Goo
Alcohols	Goo
Alkalis	Goo
Aromatic hydrocarbons	Goo
Greases and Oils	Goo
Halogenated Hydrocarbons	Goo
Ketones	Goo

d d d d **Physical Properties** d bd Density ($g \text{ cm}^{-3}$) 1.36 bd Flammability

Electrical Properties

Dielectric constant @1MHz 3.2 @ Dielectric strength (kV mn 1)160 @ Thermal Properties Dissipation factor @ 1kHz v.005 Dissipation factor @ 1MHz 10^{14} Surface resistivity (Ohm/so/) Volume resistivity (Ohmor) 10^{15}

Resist Water absorption (%) 0.4

Thermal conductivity @23C (Wm⁻¹K⁻¹) 0.15 Upper working temperature (C) 155

→ 4 kV/25µm

d-Pool Coefficient of friction 0.27 - biax film Elongation at break (%)60 - biax film Consile modulus (GPa) 5-5.5 - biax film Tensile strength (MPa) 200 - biax film VTM-2 - UL94, 0.075mm Optical transmission (%)84 @ 0.075mm

0.0048 Coefficient of thermal expansion (x10⁻⁶ K⁻¹)20-21 - bia

Taken from Tejin DuPont Films

Item		Unit	Q51 Type							
Thickness		μm	12	16	25	38	50	75	100	250
Tanaila atuanath	MD	MDa	310	310	310	270	270	270	270	210
rensile scrength	TD	- Mira	310	310	310	270	270	270	270	210
Tonsilo elemention	MD	04	85	85	85	90	90	90	100	120
Tensile elongation	TD	70	85	85	85	90	90	90	100	120
Thermal Shrinkage	MD	04	1.0	1.0	0.8	0.6	0.6	0.4	0.4	0.4
(150 deg C × 30 mins.)	TD	70	0.1	0.1	0.1	0.1	0.1	0.1	0.1	0.1
Thermal Shrinkage	MD	04	2.6	2.6	2.5	1.3	1.3	1.0	270 100 100 100 0.4 0.1 1.0 1.0 1.0 2.3 0.4 0.1 0.2 0.3 0.4	0.8
(200 deg C × 10 mins.)	TD	70	3.5	3.0	3.0	1.3	1.2	1.0	1.0	0.4
Breakdown voltage		kV/mm	-		300	250	250	200	180	-
Coefficient of friction	μs		0.4	0.4	0.4	0.4	0.4	0.4	0.4	0.4
	μk		0.3	0.3	0.3	0.3	0.:	0.3	0.3	0.3
Haze		%	8.0	10.0	13.0	14.0	150	25.0	28.0	43.0

Comparison of tensile strength to other materials:

→ 7.5 kV/25µm → 18 kV/100 µm

MATERIAL	Yield strength	Youna's modulus
PEN	> 200 MPa	5 – 13 GPa (higher value at 77K)
Copper	~70 Mpa	130 GPa
Stainless st.	400 – 550 Mpa	~ 200 GPa
HDPE	15 – 40 Mpa	~ 3 GPa
PET	55 Mpa	~ 1 GPa
Kapton (with Carbon fibre)	85 (140) Mpa	2.5 GPa





Applications of PEN

Used in a wide range of applications. Mainly electronics



Food insdustry: Bottles



Sports: canvas for sailing boats



Entertainment: membranes for headphones



Electronics: Capacitors





金属化聚萘乙酯膜表面安装直流固定电容器(PEN) Metallized polyethylene naphthalate film surface mounted D.C. capacitor (Stacked version)

■ 外形图 Outline Drawing



- 特点
- 采用无外封装叠片式技术,体积小
- 性能稳定,具有良好的温度特性、频率特性、
- 电压特性、时间稳定性和防潮特性
- 可靠性高,自愈性好
- 无压电效应,无极性,无非线性失真
- 等效串联电阻低,噪音电平低
- 抗脉冲能力强
- 抗热冲击、抗机械冲击能力强



Features

- Uncoated, stacked construction, small size
- Stability versus temperature, frequency, voltage, time and humidity
- Reliable quality due to self-healing effect
- No piezoelectric effect, non-polar construction,
- non-linearity distortion
- Low ESR, low noise level
 High dv/dt ability
- High dv/dt ability
- No cracking under thermal impact or mechanical bump



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Special Article - Tools for Experiment and Theory

High voltage capacitors for low background experiments

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Fig. 4 Long-term measurement of the leakage current with the capacitor biased to 5 kV at 77 K. The right hand projection is a binned frequency distribution showing the Gaussian profile

HV capacitor tested in LAr for several days: No (micro-)discharges observed

\rightarrow Can be used for HV cables!



B. Majorovits

Commercial availability of PEN



Films in different thicknesses (1.3um – 0.25mm)

Tejin DuPunot Films, Goodfellows, GTS

(for example: 5m x 0.3m EUR 551)



Granules, ca. 5mm Goodfellows (2 kg EUR 384)



Rods, diameter: 12mm or 25mm BLACK! Goodfellows (I:500mm, d: 25mm, EUR 500)

Use for further processing to flat band cables

Challenge: Radiopurity of limnation processes!



Use for further processing to structural materials

Easy to make plates of 5 x 500 x 500 mm3 plates using conventional injection molding

(for example Fraunhofer Institute for Chemical Technolgy)

Immediate use for structural material (provided its clean)

Would be custom made material: remove additives



Radiopurity of PEN

Samples received from Ami Doduco

ICPMS meaurements

	Peso	K	Pb	Th	U	⁴⁰ K	²³² Th	²³⁸ U
	[%]	[ppb]	[ppb]	[ppt]	[ppt]	[mBq/kg]	[mBq/kg]	[mBq/kg]
Pure PEN	100	< 393	26 ± 3	< 16	< 16	< 12	< 0.07	< 0.2
		i						
Cu	77.59	3210 ± 160	16.3 ± 0.1	< 124	134 ± 2			
Cr	0.21	< 183	1.4 ± 0.2	-7.3 ± 3.7	<7			
PEN	16.2	< 66	4.2 ± 0.4	< 3	< 3			
Whole sample		3210_{-160} + 170	21.9 ± 0.5	7 _ 4 + 42	134_{-2}^{+3}	97 ± 5	$0.03_{-0.02}^{+0.17}$	$1.66_{-0.02}$ + 0.04
Cu	82.03	1646 ± 21	7.0 ± 0.4	< 135	< 135			
Cr	0.25	< 270	3.5 ± 0.2	<10	<10			
PEN	17.72	< 85	4.3 ± 0.3	<3	<3	1.0.0		
Whole sample		1646 - 21 + 97	14.8 ± 0.5	<148	< 148	$49.9_{-0.6}^{+2.9}$	< 0.6	< 1.8
Cu	17.29	1290 ± 170	8.6 ± 0.4	< 76	< 76			
Cr	1.68	< 3041	10.4 ± 0.5	< 122	< 122			
PEN	81.03	<365	55 ± 3	< 144	< 90			
Whole sample		1290 - 170 + 1040	74 ± 3	< 342	< 288	39_{-5}^{+35}	< 1.4	< 3.6
					·	-		
Pure PET	100	480 ± 110	53 ± 5	522 ± 52	3714 ± 37	14.6 ± 3.3	2.1 ± 0.2	46.1 ± 0.5

 \rightarrow No 228Th, 226Ra detectable by gamma screening





Radiopurity of PEN

The second secon

PEN received GTS-Flexible

			⁴⁰ K [mBq/kg]	²³² Th [mBq/kg]	²³⁸ U [mBq/kg]
PEN (from	M.L.big	γ-spectroscopy	510 ± 20	$\textbf{135}\pm\textbf{3}$	242 ± 3
roll)		ICP-MS	$\textbf{370} \pm \textbf{50}$	110 ± 10	200 ± 30

→ Massive contaminations!



Radiopurity of PEN

Teonex Q51 (PEN) received from Tejin DuPont Films:



GERDA sample: Gamma screening (Baksan) : Ra-226: <2.0 mBq/kg (90% C.L.) Th-228: <1.4 mBq/kg (90% C.L.) K-40: <3.6 mBq/kg (90% C.L.)

	Kapton(average)	PEN3
K [mBq/Kg]	<47	<12.4
Th [mBq/Kg]	$0.45_{-0.15}^{+0.15}$	$0.06_{-0.02}^{+0.06}$
U [mBq/Kg]	10_{-3}^{+3}	<0.40

CUORE sample: Gamma screening: Ra-226: <1.3 mBq/kg (90% C.L.) Th-228: <1.0 mBq/kg (90% C.L.) K-40: <13.2 mBq/kg (90% C.L.)

→ Radiopure PEN can be procured. However, careful screening is obligatory!





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Electrical characterization of the low background Cu-PEN links of the CUORE experiment



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PEN lamination process for GERDA proved to work:

- 1) Procure TEONEX Q51 (DuPon Teijin)
 - 2) Sputter 150nm NiCr tie coat (GFO)
 - 3) Sputter 2µm Cu (GFO)
- 4) Electroplate 45µm of Cu and NiAu finishing (Lüberg)
- 5) Processing into FPC boards (Lüberg) NiCr tie coat problematic!



R&D time: 2008-2010





Contacts require bending. All 18 contacts good!







ICPMS analysis performed by S. Nisi et al at LNGS:

		Metal Layer	PEN	Whole sample N2
K	ppb	<10000	$3700\pm_{800}^{+1100}$	3700 -800 +3500
Pb	ppb	24000±3600	260±40	24000±3600
Th	ppt	2300±350	1000±50	3300±400
U	ppt	1000_{-200}^{+700}	500±50	1500.250+750

→ PEN can be used as very front end cable Lamination processe have to be controlled





PEN Scintillation properties



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Evidence of deep-blue photon emission at high efficiency by common plastic

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PEN Scintillation properties

Material Supplier 7 Base Density Refractive index Light output ~ 1 Wavelength max. emission 2 1.8 1.6 1.4 1.2 $2^{207}Bi ($ K-line converted	Polyethylene naphthalate Teijin Chemicals $(C_{14}H_{10}O_4)_n$ 1.33 g/cm^3 1.65 0500 photon/MeV 425 nm	Organic scintillator (ref. [14]) Saint-Gobain $(C_9H_{10})_n$ 1.03 g/cm^3 1.58 10000 photon/MeV	Plastic bottle (ref. [13]) Teijin Chemicals $(C_{10}H_8O_4)_n$ 1.33 g/cm^3 1.64
Supplier \Box Base Density Refractive index Light output ~ 1 Wavelength max. emission 2 1.8 1.6 1.4 1.2 $2^{207}Bi ($ K-line conv	$\begin{array}{c} \text{Feijin Chemicals} \\ (\text{C}_{14}\text{H}_{10}\text{O}_4)_n \\ 1.33\text{g/cm}^3 \\ 1.65 \\ 0500 \text{ photon/MeV} \\ 425\text{nm} \end{array}$	Saint-Gobain $(C_9H_{10})_n$ 1.03 g/cm^3 1.58 10000 photon/MeV	Teijin Chemicals $(C_{10}H_8O_4)_n$ 1.33 g/cm^3 1.64
Base Density Refractive index Light output ~ 1 Wavelength max. emission 2 1.8 1.6 1.4 1.2 ^{207}Bi (K-line conversion	$(C_{14}H_{10}O_4)_n$ 1.33 g/cm^3 1.65 0500 photon/MeV 425 nm	$(C_9H_{10})_n$ 1.03 g/cm ³ 1.58 10000 photon/MeV	$(C_{10}H_8O_4)_n$ 1.33 g/cm ³ 1.64
Density Refractive index Light output ~ 1 Wavelength max. emission 1.6 1.6 1.4 1.2 207Bi (K-line converse	$1.33 { m g/cm}^3$ 1.65 0500 photon/MeV 425 nm	$\begin{array}{c} 1.03\mathrm{g/cm^3}\\ 1.58\\ 10000~\mathrm{photon/MeV} \end{array}$	$1.33 \mathrm{g/cm^3}$ 1.64
Refractive index Light output ~ 1 Wavelength max. emission 2 1.8 1.6 1.4 1.2 $2^{207}Bi$ (K-line converted	1.65 0500 photon/MeV $425\mathrm{nm}$	1.58 10000 photon/MeV	1.64
Light output ~ 1 Wavelength max. emission 2 1.8 1.6 1.4 1.2 $2^{207}Bi ($ K-line converted	$\begin{array}{c} 0500 \hspace{0.1cm} \mathrm{photon/MeV} \\ 425 \hspace{0.1cm} \mathrm{nm} \end{array}$	10000 photon/MeV	
Wavelength max. emission	$425\mathrm{nm}$	± /	$\sim 2200 \text{ photon/MeV}$
2 1.8 1.6 1.4 1.2 ²⁰⁷ Bi (K-line conv		$425\mathrm{nm}$	$380\mathrm{nm}$
$\begin{array}{c} 1 \\ 0.8 \\ 0.6 \\ 0.4 \\ 0.2 \\ 0 \\ 0 \\ 2000 \\ 4000 \\ 6000 \\ 8000 \\ 10 \\ 10 \\ 10 \\ 10 \\ 10 \\ 10$	PEN BC-408 PET 976keV) ersion electron	1 0.9 0.9 0.7 0.8 0.7 0.6 0.5 0.4 0.5 0.4 0.3 0.2 0.1 0.2 0.1 0.2 0.1 0.2 0.1 0.2 0.1 0.2 0.1 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2	PEN BC-408 PET



How could PEN help us?

- PEN can be clean
- PEN can be laminated on
- PEN has good mechanical properties
 - PEN scintillates

Maybe we can replace most of the structural materials with self vetoing PEN?

This could include:

Detector end cap Readout and HV cables











CONCLUSIONS:

- PEN has rather good mechanical properties
- PEN can satisfy low background requirements
- PEN is suitable for HV
- \rightarrow PEN is promising material for flexible cables
- PEN does seem to scintillate very well
 →Could PEN be used as self vetoing structural material?

→ Needs further R & D

